

FORM PTO-1449 INFORMATION DISCLOSURE STATEMENT				Atty Docket MAE 286		Application No. To Be Assigned	
				Applicant Toshio NAGATA			
				Filing Date June 27, 2003		Group Unit To Be Assigned	
U.S. PATENT DOCUMENTS							
Examiner Initial		Document Number	Date	Name	Class	Sub-Class	Filing Date
	AA						
	AB						
	AC						
	AD						
	AE						
	AF						
	AG						
FOREIGN PATENT DOCUMENTS							
		Document Number	Date	Country	Class	Sub-Class	Translation
<i>AB</i>	AH	08-255905	10/01/96	<i>Japan</i>	—	—	Abstract
	AI						
	AJ						
	AK						
	AL						
	AM						
	AN						
OTHER (Including Author, Title, Date, Pertinent Pages, etc.)							
<i>AB</i>	AO	James C.M. Hwang, "Relationship between gate lag, power drift, and power slump of pseudomorphic high electron mobility transistors", Solid-State Electronics 43 (1999), pp. 1325-1331					
	AP						
	AQ						
	AR						
Examiner <i>[Signature]</i>				Date Considered <i>08/08/04</i>			
EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; draw line through citation if not in conformance and not considered. Include copy of this form with next communication to Applicant.							